

Excellent Integrated System Limited

Stocking Distributor

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ON Semiconductor MM3Z3V3ST1

For any questions, you can email us directly: sales@integrated-circuit.com



MM3Z2V4ST1 SERIES

Zener Voltage Regulators

200 mW SOD-323 Surface Mount Tight Tolerance Portfolio

This series of Zener diodes is packaged in a SOD-323 surface mount package that has a power dissipation of 200 mW. They are designed to provide voltage regulation protection and are especially attractive in situations where space is at a premium. They are well suited for applications such as cellular phones, hand-held portables, and high density PC boards.

Specification Features:

- Standard Zener Breakdown Voltage Range –
 2.4 V to 33 V
- Steady State Power Rating of 200 mW
- Small Body Outline Dimensions:

0.067" x 0.049" (1.7 mm x 1.25 mm)

- Low Body Height: 0.035" (0.9 mm)
 Package Weight: 4.507 mg/unit
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- Tight Tolerance V_Z
- Pb–Free Packages are Available

Mechanical Characteristics:

CASE: Void-free, transfer-molded plastic

FINISH: All external surfaces are corrosion resistant

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

LEADS: Plated with Pb–Sn or Sn only (Pb–Free) **POLARITY:** Cathode indicated by polarity band

FLAMMABILITY RATING: UL 94 V-0

MOUNTING POSITION: Any

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) @ T _A = 25°C Derate above 25°C	P _D	200 1.5	mW mW/°C
Thermal Resistance from Junction–to–Ambient	$R_{ heta JA}$	635	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 Minimum Pad.

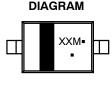


ON Semiconductor®

http://onsemi.com







MARKING

SOD-323 CASE 477 STYLE 1

XX = Specific Device Code

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MM3ZxxxST1	SOD-323	3000/Tape & Reel
MM3ZxxxST1G	SOD-323 (Pb-Free)	3000/Tape & Reel
MM3ZxxxST3	SOD-323	10,000/Tape & Reel
MM3ZxxxST3G	SOD-323 (Pb-Free)	10,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

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Datasheet of MM3Z3V3ST1 - DIODE ZENER 3.43V 200MW SOD323

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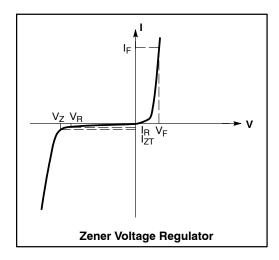
MM3Z2V4ST1 SERIES

ELECTRICAL CHARACTERISTICS

($T_A = 25^{\circ}C$ unless otherwise noted,

 $V_F = 0.9 \text{ V Max.} \otimes I_F = 10 \text{ mA for all types}$

Symbol	Parameter					
V _Z	Reverse Zener Voltage @ I _{ZT}					
I _{ZT}	Reverse Current					
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}					
I _{ZK}	Reverse Current					
Z _{ZK}	Maximum Zener Impedance @ I _{ZK}					
I _R	Reverse Leakage Current @ V _R					
V _R	Reverse Voltage					
I _F	Forward Current					
V _F	Forward Voltage @ I _F					
ΘV_Z	Maximum Temperature Coefficient of V _Z					
С	Max. Capacitance @V _R = 0 and f = 1 MHz					



ELECTRICAL CHARACTERISTICS ($V_F = 0.9 \text{ Max} @ I_F = 10 \text{ mA}$ for all types)

T		Test	Test Zener Volta		tage VZ = 0.5	Z _{ZT} I _Z = IZT @ 10%	Max IR @ VR		d _{VZ} /dt (mV/k) @ I _{ZT1} = 5 mA		C pF Max @
Device*	Device Marking	Current Izt mA	Min	Max	mA Ω Max	Mod Ω Max	μΑ	V	Min	Max	V _R = 0 f = 1 MHz
MM3Z3V3ST1, G	T5	5.0	3.32	3.53	1000	95	5.0	1.0	-3.5	0	450
MM3Z3V9ST1, G	T7	5.0	3.89	4.16	1000	90	3.0	1.0	-3.5	-2.5	450
MM3Z4V3ST1, G	T8	5.0	4.17	4.43	1000	90	3.0	1.0	-3.5	0	450
MM3Z4V7ST1, G	Т9	5.0	4.55	4.75	800	80	3.0	2.0	-3.5	0.2	260
MM3Z5V1ST1, G	TA	5.0	4.98	5.2	500	60	2.0	2.0	-2.7	1.2	225
MM3Z5V6ST1, G	TC	5.0	5.49	5.73	200	40	1.0	2.0	-2.0	2.5	200
MM3Z6V2ST1, G	TE	5.0	6.06	6.33	100	10	3.0	4.0	0.4	3.7	185
MM3Z6V8ST1, G	TF	5.0	6.65	6.93	160	15	2.0	4.0	1.2	4.5	155
MM3Z7V5ST1, G	TG	5.0	7.28	7.6	160	15	1.0	5.0	2.5	5.3	140
MM3Z8V2ST1, G	TH	5.0	8.02	8.36	160	15	0.7	5.0	3.2	6.2	135
MM3Z9V1ST1, G	TK	5.0	8.85	9.23	160	15	0.5	6.0	3.8	7.0	130
MM3Z10VST1, G	WB	5.0	9.80	10.20	160	15	0.5	6.0	4.5	8.0	130
MM3Z12VST1, G	TN	5.0	11.74	12.24	80	25	0.1	8.0	6.0	10	130
MM3Z15VST1, G	TP	5.0	14.34	14.98	80	40	0.1	11	8.8	12.7	130
MM3Z16VST1, G	TU	5.0	15.85	16.51	80	40	0.05	11.2	10.4	14	105
MM3Z18VST1, G	TW	5.0	17.56	18.35	80	45	0.05	12.6	12.4	16	100
MM3Z22VST1G	WP	5.0	21.54	22.47	100	55	0.05	15.4	16.4	20	85
MM3Z27VST1G	WQ	5.0	26.19	27.53	300	80	0.05	18.9	21.4	25.3	70
MM3Z33VST1G	WR	5.0	32.15	33.79	300	80	0.05	23.2	27.4	33.4	70

^{*}The "G" suffix indicates Pb-Free package available.



MM3Z2V4ST1 SERIES

TYPICAL CHARACTERISTICS

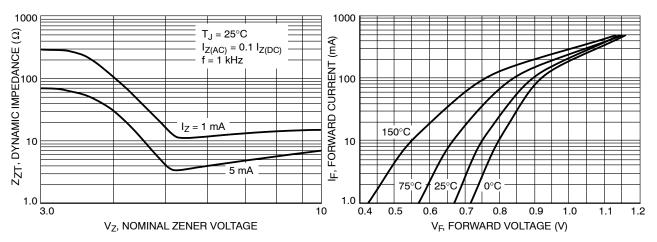


Figure 1. Effect of Zener Voltage on Zener Impedance

Figure 2. Typical Forward Voltage

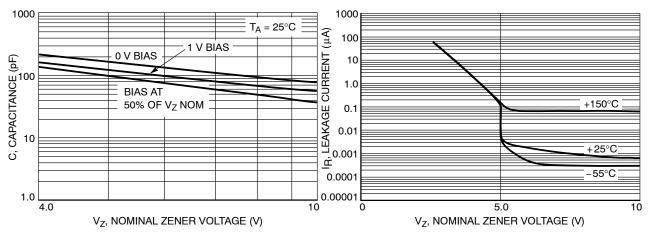


Figure 3. Typical Capacitance

Figure 4. Typical Leakage Current

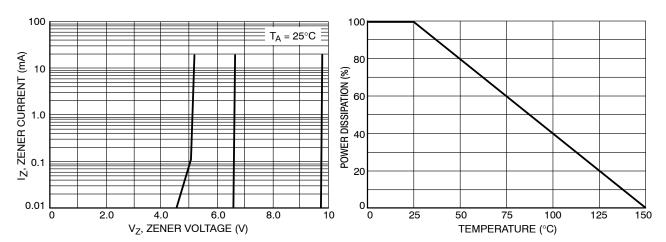


Figure 5. Zener Voltage versus Zener Current (V_Z Up to 9 V)

Figure 6. Steady State Power Derating



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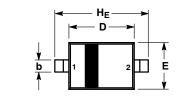
Datasheet of MM3Z3V3ST1 - DIODE ZENER 3.43V 200MW SOD323

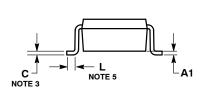
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PACKAGE DIMENSIONS

SOD-323 CASE 477-02 **ISSUE G**







NOTES:

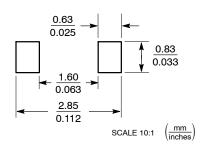
- VIES.
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETERS.
- CONTROLLING DIMENSION: MILLIME 1EHS.
 LEAD THICKNESS SPECIFIED PER L/F DRAWING
 WITH SOLDER PLATING.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD
 FLASH, PROTRUSIONS OR GATE BURRS.
 DIMENSION L IS MEASURED FROM END OF
- RADIUS

	MIL	LIMETE	ERS	INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.90	1.00	0.031	0.035	0.040	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A3	0.15 REF			0.006 REF			
b	0.25	0.32	0.4	0.010	0.012	0.016	
С	0.089	0.12	0.177	0.003	0.005	0.007	
D	1.60	1.70	1.80	0.062	0.066	0.070	
E	1.15	1.25	1.35	0.045	0.049	0.053	
L	0.08			0.003			
HE	2.30	2.50	2.70	0.090	0.098	0.105	

STYLE 1: PIN 1. CATHODE

2. ANODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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